Quantitative Mapping of Strain, Polarization, and Octahedral Distortion at unit cell resolution by Scanning Electron Diffraction

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Scanning diffraction methods experiments in transmission electron microscopy have undergone substantial growth in recent years, due in part to the availability of high speed pixelated detectors with reasonable dynamic range. This capability enables new experiments that combine the benefits of position averaged convergent beam electron (PACBED) [1] with accurate partitioning of diffraction data into precise unit cell bins. A recent example of this combined technique is the quantitative determination of composition at projected unit cell resolution in SrTiO₃-La₀.7Sr₀.3MnO₃ multilayers from purely elastic scattering (Figure 1) [2]. PACBED has also been shown to be sensitive to the direction of polarization [3] and degree of octahedral tilt [4]. However, the optimal experimental conditions and limits of precision for mapping these quantitates quantitatively at unit cell resolution have yet to be fully explored.

We have initially focused on two model systems to independently address the quantitative error in measurements of polarization and octahedral rotation at single projected unit cell resolution. BaTiO₃ films have been grown on NdScO₃ (110), SmScO₃ (110), GdScO₃ (110) substrates using epitaxial strain to vary the degree of polarization from ~25 µC/cm² to ~35 µC/cm². In addition, SrRuO₃ films have been grown on SrTiO₃ substrates with and without a buffer layer of GdScO₃ to modulate the degree of octahedral rotation in the surface film (Figure 2) [5], where the degree of rotation is expected to decay within a few unit cells from the interface. In order to verify the quantitative accuracy of these methods and determine optimal experimental parameters, we have performed a large set of PACBED simulations using implementations of the multislice [6] and µSTEM [7] methods. The use of machine learning algorithms for both data analysis and to facilitate lossless data compression will also be discussed [8].

References:

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Figure 1. Elastic scattering composition measurements of (LaMn)$_x$(SrTi)$_{1-x}$O$_3$  

a) HAADF image  

b) inverse of reconstructed bright-field  

c) composition maps at unit cell resolution from best-fit matches to PACBED simulations  

d) composition averaged perpendicular to the growth direction

Figure 2.  

a) Structural model of BaTiO$_3$ in the centrosymmetric and polarized (35 μC/cm$^2$) states. PACBED simulations shown at right for 300 kV electrons at 10 mrad semi-convergence for 12 nm and 20 nm sample thickness. Difference maps plotted from -0.6% to 0.6% of the incident probe intensity.  

b) Structural model of SrRuO$_3$ film as grown on a 10 nm thick GdScO$_3$ buffer layer (top) and pure SrTiO$_3$ substrate (bottom). PACBED simulations shown at right for 300 kV electrons at 10 mrad semi-convergence for 12.6 nm and 28.4 nm sample thickness. Difference maps plotted from -0.3% to 0.3% of the incident probe intensity.